Intersubband-transition-induced phase matching

Gilad Almogy, Mordechai Segev,* and Amnon Yariv
California Institute of Technology, Pasadena, California 91125

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We suggest the use of the refractive-index changes associated with the intersubband transitions in quantum wells for phase matching in nonlinear materials. An improvement in the conversion efficiency of mid-IR second-harmonic generation by almost 2 orders of magnitude over non-phase-matched bulk GaAs is predicted. We also show that the linear phase contributions of intersubband transitions used for resonant enhancement of second-harmonic generation must be considered, as they could limit the conversion efficiency by increasing the phase mismatch on one hand or offset the bulk’s dispersion and lead to phase matching on the other.

The second-harmonic generation (SHG) efficiencies of nonlinear materials are often limited by their coherence lengths,1 and schemes for phase matching or quasi-phase matching2 need to be employed for reasonable conversion efficiencies to be achieved. Recently it was demonstrated that the refractive index of bulk material may be selectively altered by the large refractive-index contributions associated with the intersubband transitions (ISBT’s) in quantum wells.3,4 In this Letter we suggest the use of these tailorable refractive-index contributions to offset the bulk’s dispersion and obtain a phase-matched material at a selected wavelength. The phase matching obtained in this manner is intrinsic and requires no external process such as quasi-phase matching or angle tuning. We examine the contribution of this technique to the conversion efficiency of mid-IR radiation in GaAs phase matched by GaAs/AlGaAs n-doped quantum wells. Both the ideal case of a bulk material embedded with quantum wells and the case that is more practical as a result of growth limitations of the TM mode in a narrow dielectric waveguide are considered.

We consider ISBT index contributions originating either from symmetric (two-level) wells, designed for phase matching only, or from asymmetric (three-level) quantum wells, designed both for resonant enhancement of the SHG and for phase matching. First we examine the former, in which the source of the SHG nonlinearity is the bulk material. Introduction into bulk material of a transition whose real part of the optical susceptibility will offset the bulk’s dispersion and obtain a phase-matched material at a selected wavelength. The wave vectors are thus modified by the large refractive-index contributions associated with the intersubband transitions (ISBT’s) in quantum wells.

The ISBT’s offsetting the bulk’s dispersion are unavoidably accompanied by loss; hence a solution of the SHG propagation equations that takes the absorption into account is necessary. Maxwell’s equations for a field of ω and 2ω frequency components (Eω and E2ω, respectively) reduce with the slowly varying amplitude approximation to

\[
\frac{dE_\omega}{dz} = -\frac{i\omega}{2\varepsilon_0 n_\omega c} dE_{2\omega} \tilde{E}_\omega^* \exp(-i\Delta k z), \quad (1a)
\]

\[
\frac{dE_{2\omega}}{dz} = -\frac{i\omega}{\varepsilon_0 n_{2\omega} c} dE_\omega \tilde{E}_{2\omega} \exp(i\Delta k z), \quad (1b)
\]

where \(n_\omega\) and \(n_{2\omega}\) are the first- and second-harmonic bulk refractive indices, respectively, \(d\) is the bulk’s SHG coefficient, and \(\Delta k = k_{2\omega} - 2k_\omega\) is defined as the phase mismatch. The real and imaginary components of the ISBT linear susceptibility, \(\chi'(\omega)\) and \(\chi''(\omega)\), are given for a two-level system as

\[
\chi(\omega) = \chi'(\omega) - i\chi''(\omega) = \frac{N \mu^2}{\varepsilon_0 \hbar} \left( \frac{\Delta\omega T_2 - i}{\sqrt{\Delta\omega^2 T_2^2 + 1}} \right), \quad (2)
\]

where \(N\) is the average electron volume density, \(\mu\) is the intersubband dipole element, \(T_2\) is the dephasing time, and \(\Delta\omega\) is the detuning of \(\omega\) from the ISBT frequency (\(\omega + \Delta\omega\) is hence the second harmonic’s detuning). The wave vectors are thus modified by the real components of the ISBT and become

\[
k_\omega^2 = \frac{\omega^2}{c^2} \left[ n_\omega^2 + \chi'(\omega) \right], \quad (3a)
\]

and the absorption, neglecting the bulk’s contribution, is given by

\[
\alpha_\omega = \frac{\omega}{2n_\omega c} \chi'(\omega), \quad (3b)
\]

Normalizing the fundamental frequency and its detuning in half-linewidth units (\(\tilde{\omega} = \omega T_2\) and \(\tilde{\Delta}\omega = \Delta\omega T_2\)), we obtain the phase-matching condition from Eqs. (1), (2), and (3a) as

\[
\frac{n_{2\omega}^2 - n_\omega^2}{2n_\omega} \approx n_\omega - n_{2\omega} = D\Delta n
\]

\[
= \frac{\chi_{\text{res}}}{2n_\omega} \left[ \frac{\Delta\tilde{\omega}}{\Delta\tilde{\omega}^2 + 1} - \frac{(\Delta\tilde{\omega} - \tilde{\omega})}{(\Delta\tilde{\omega} - \tilde{\omega})^2 + 1} \right], \quad (4)
\]

where \(\chi_{\text{res}}\) is the on-resonance (imaginary) susceptibility (\(\Delta\omega = 0\) in Eq. (2)). When phase matching (\(\Delta k = 0\)) is maintained, Eqs. (1) are solved as

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where we have neglected the depletion of the first harmonic that is due to SHG ($E_{2w} \ll E_{0}$). From Eq. (5) we find the optimal conversion distance as

$$z_{\text{max}} = \frac{1}{\alpha_{2w} - 2\alpha_{w}} \ln \left( \frac{2\alpha_{w}}{\alpha_{2w}} \right),$$

(6a)

yielding a maximal (intensity) conversion efficiency of

$$\eta(\alpha_{\text{max}}) = \frac{I_{2w}(z_{\text{max}})}{I_{w}(0)} = 2 \left( \frac{\mu_0}{\epsilon_0} \right)^{3/2} \frac{\omega^2 d^2}{n_{2w} n_{2w}^2} \left[ 1 - \left( \frac{2\alpha_{w}}{\alpha_{2w}} \right)^{2\alpha_{w} - 2\alpha_{w}} \right] \frac{I_{w}(0)}{\Delta \omega},$$

(6b)

where $I_{w}(0)$ is the incident first-harmonic intensity. By substituting Eq. (2) and (3) and relation (4) into Eq. (6b), we find a maximum for the conversion efficiency at $\Delta \omega = \omega/2$. Thus when the resonant transition is halfway between the fundamental and the second harmonic the conversion efficiency is given by

$$\eta_{\text{max}} = \frac{1}{2\alpha^2} \left( \frac{\mu_0}{\epsilon_0} \right)^{3/2} \frac{d^2 c^2}{n_{2w} n_{2w}^2} \left( \frac{\alpha}{\Delta n} \right)^2,$$

(7a)

while the optimal propagation length for obtaining this maximal efficiency is

$$z_{\text{max}} = \frac{c T_2}{2 \Delta n} = \frac{\omega \lambda}{\pi 4 \Delta n} = \frac{\omega l_c}{\pi l_c},$$

(7b)

where $(l_c = \lambda/4\Delta n)$ is the bulk's coherence length. The phase-matching condition becomes

$$\Delta n = \frac{2}{n_w^2} \frac{N \mu^2}{\hbar \omega \epsilon_0} + 4 + \frac{2}{\alpha^2} = \frac{1}{n_w^2} \frac{N \mu^2}{\hbar \omega \epsilon_0},$$

(7c)

and the conversion efficiency may thus be enhanced by a factor of as much as $\left( \frac{\omega}{2\alpha} \right)^3$ over the non-phase-matched case. The enhancement is dependent only on the frequency-to-broadening ratio. For AlGaAs/GaAs quantum wells, $\omega$'s of $\sim 25-50$ are typical, and the index mismatch is $\Delta n_{\text{AlGaAs}} \approx 0.03$ (Ref. 9) for a first harmonic of 10.6 $\mu$m doubled to 5.3 $\mu$m, leading to an improvement of almost 2 orders of magnitude over non-phase-matched bulk. To prevent saturation of the transitions, we must limit the incident optical intensity to $\omega/2 \alpha^3$ times the ISBT saturation intensity, but practically it will be limited by surface phenomena to $\sim 10$ MW/cm$^2$. This leads to a maximal conversion efficiency of approximately 3%, with $d = 3.4 \times 10^{-21}$ m/V for GaAs. The maximal refractive-index dispersion that may be compensated for is given by relation (7c) as a function of the average electron density and of the optical dipole matrix elements. AlGaAs/GaAs wells with a volume density of $10^{18}$ cm$^{-3}$ and dipole matrix elements of 2 nm need a filling factor of less than 10% to correct the dispersion of bulk GaAs. Unfortunately current technology limits the growth of high-quality epitaxial layers to $\sim 10$ $\mu$m, making waveguiding necessary for longer interaction distances. The refractive-index contribution of ISBT's located in the core of a dielectric waveguide must be tailored to equalize the phase velocities of the first- and second-harmonic modes. Using a numerical solution of the TM modes in arbitrarily shaped dielectric waveguides, we find that phase matching should be obtainable by use of ISBT's, provided that sufficient confinement is achieved. Figure 1 shows a possible example of a phase-matched waveguide.

The refractive-index correction obtained by a single ISBT halfway between the first and second harmonics is insensitive to the transition's frequency to first order, making this phase-matching technique tolerant of quantum-well growth inaccuracies (ISBT frequency variations). The magnitude of the ISBT, however, has to be obtained with an accuracy of at least $\pi/\omega$ to increase the coherence length above the optimal propagation length. This magnitude is correctable by electron injection mechanisms, which are thus also the way tuning may be achieved. The phase matching is relatively broadband and can be tailored to cover most of the CO$_2$ laser's spectral range, as shown in Fig. 2.
The accumulated phase difference at a distance of the inverse of the absorption coefficient is therefore $2 \Delta \phi$. Thus, when the normalized detuning ($\Delta \phi$) is not significantly smaller than $\pi/2$, the ISBT phase mismatch may limit the maximal conversion efficiency, even for propagation distances shorter than the bulk’s coherence length. In Fig. 3 we give an example of the ISBT’s of a three-level quantum well, both enhancing SHG and offsetting the bulk’s dispersion. The applicability of such a technique is limited by its high sensitivity to well parameters and by the saturation of near-resonant ISBT’s, but the phase mismatch that may be caused by the ISBT’s dispersion must be considered in any attempt to increase significantly the resonantly enhanced conversion efficiencies. Only on-resonant, or equally detuned, transitions of equal strength will not include such a phase mismatch.

In summary, we have considered the implications of the ISBT’s index contributions to SHG and suggested a novel phase-matching technique. This technique replaces the coherence length limitations on SHG conversion efficiencies by absorption limitations — with a potential gain proportional to the transition’s frequency-to-linewidth ratio squared. This technique may be applied to any material in which a desired wavelength transition with a sufficient refractive-index correction can be introduced. With current technology, the use of ISBT phase matching may lead to an improvement of almost 2 orders of magnitude in the bulk SHG of 5-μm radiation in GaAs, with further improvement dependent on the availability of narrower linewidth transitions.

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References